

A115 Series

December 1993

3A, 50V - 600V Diodes

Features

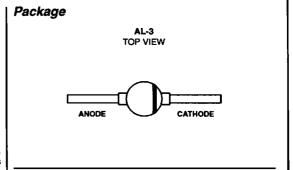
- · Glass Passivated Junction
- · Fast Recovery Times
- . Low Forward Voltage Drop, High-Current Capability
- Low Reverse Current Leakage
- High Surge Current Capability

Description

The Harris A115A, A115B, A115C, A115D, A115E, A115F, and A115M are fast-recovery silicon rectifiers (t_{RR} = 250ns max.) featuring low forward voltage drop, high-current capability. They use glass passivated epitaxial construction.

These rectifiers are intended for TV deflection, inverter, high-frequency power supplies, energy recovery, and output rectification.

These types are supplied in unitized-glass hermeticallysealed AL-3 package.



Symbol



| | A115F | A115A | A115B | A115C | A115D | A115E | A115M | UNITS |
|---|-------------|-------|-------|-------|-------|-------|-------|-------|
| /laximum Peak (Repetitive) | | | | | | | | |
| Reverse VoltageVRRM | 50 | 100 | 200 | 300 | 400 | 500 | 600 | ٧ |
| Maximum RMS Input | | | | | | | | |
| (Supply) Voltage V _{RMS} | 35 | 70 | 140 | 210 | 280 | 350 | 420 | V |
| Maximum DC Reverse | | | | | | | | |
| Blocking) Voltage V _{R(DC)} | 50 | 100 | 200 | 300 | 400 | 500 | 600 | ٧ |
| Maximum Average Forward Output Current | | | | | | | | |
| Lead Length = 0.375in. (9.5mm); | | | | | | | | |
| $T_A = -55$ °CI _O | 3 | 3 | 3 | 3 | 3 | 3 | 3 | Α |
| Maximum Peak Surge (Non-Repetitive) | | | | | | | | |
| Forward Current: | | | | | | | | |
| For 8.3ms Half Sine Wave, | | | | | | | | |
| Superimposed on Rated Load I _{FSM} | 100 | 100 | 100 | 100 | 100 | 100 | 100 | Α |
| Operating Junction and | | | | | | | | |
| Storage Temperature | -65 to +175 | | | | | | | °C |
| NOTE: | | | | | | | | |

^{1.} For capacitive load derate current by 20%.

Specifications A115 Series

Electrical Specifications T_A = +25°C, Unless Otherwise Specified

| | | LIMIT | | | | |
|--|-----------------|-------|-----|-----------------|-------|--|
| PARAMETERS | SYMBOL | MIN | TYP | MAX | UNITS | |
| Maximum Instantaneous Forward-Voltage Drop At 3A | V _F | - | - | 1.3 | ٧ | |
| Maximum Full-Load Reverse Current | | | | | | |
| At Average Full-Cycle, Lead Length = 0.375 in. (9.5mm) $T_A = +25^{\circ}C$ | I _R | - | | 2 | μА | |
| At Average Full-Cycle, Lead Length = 0.375 in. (9.5mm) T _A = +150°C | I _R | • | - | 100 | μА | |
| Maximum DC Reverse Current at Maximum DC Blocking Voltage | I _R | - | - | 5 | μА | |
| Maximum Reverse Recovery Time | | | | | | |
| At $I_F = 0.5A$, $I_R = 1A$, $I_{RR} = 0.25A$ | t _{RR} | - | | 150 (Note 1) | μs | |
| Typical Junction Capacitance At Frequency = 1MHz and Applied Reverse Voltage = 4V | С | - | 40 | - | pF | |

NOTE:

1. 250ns for A115M

Typical Performance Curves

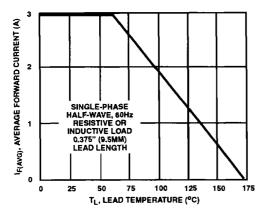


FIGURE 1. MAXIMUM AVERAGE FORWARD OUTPUT CURRENT CHARACTERISTIC

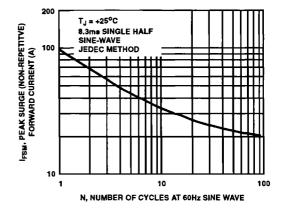
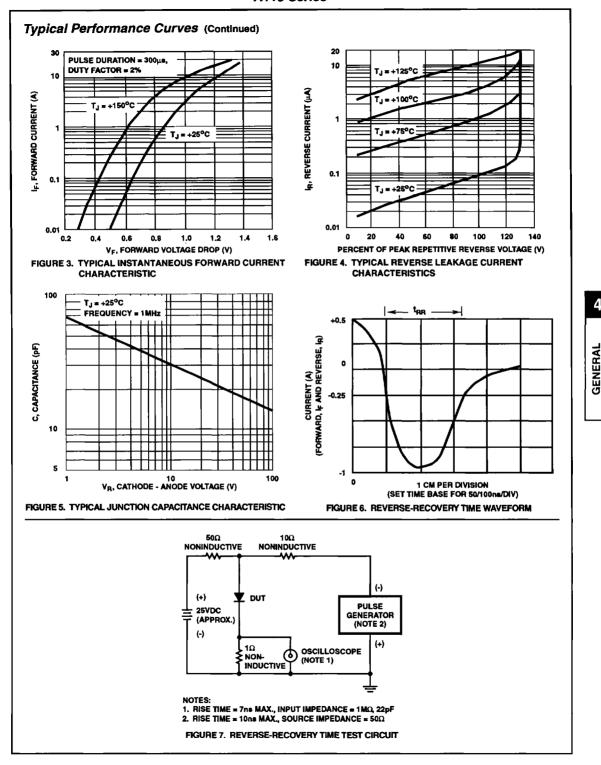


FIGURE 2. MAXIMUM PEAK SURGE (NON-REPETITIVE)
FORWARD CURRENT CHARACTERISTIC



PURPOSE DIODES